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Inclosure Material:	
Metal	
Overall Length:	
1.453 inches	
Mounting Facility Quantity:	
1	
Joint Electronic Device Engineering Council/jedec/case Outline Designation:	
Do-5	
Electrode Internally-electrically Connected To Case:	
Cathode	
Mounting Method:	
Threaded stud	
Features Provided:	
Burn in and hermetically sealed case and quality assurance level tx and reverse polarity	
Overall Width Across Flats:	
Between 0.667 inches and 0.687 inches	
Thread Size:	
0.250 inches	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
4.3 regulator voltage	
Voltage Tolerance In Percent:	
-5.0/+5.0	
Current Rating Per Characteristic:	
11.05 amperes all primaries horsepower metric and 2.90 amperes repetitive peak forward	current
Power Rating Per Characteristic:	
50.0 watts small-signal input power, common-collector preset	
Maximum Operating Tempurature Per Measurement Point:	
150.0 degrees celsius case	
Test Data Document:	
81349-mil-prf-19500 standard (includes industry or association standards, individual manu	ıfactureer standards, etc.).
Thread Series Designator:	
Unf	
Terminal Type And Quantity:	
1 tab, solder lug and 1 threaded stud	
Shelf Life:	
N/a	
Unit Of Measure:	
-	
Demilitarization:	
No	

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Mil-std (military Standard):

Mil-prf-19500 spec.